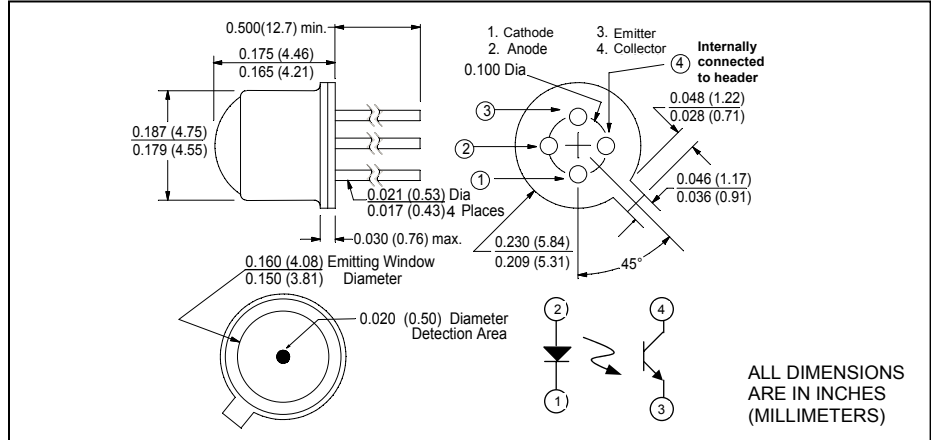


CLI710

IRED – Phototransistor Reflective Object Sensor



March, 2002



ALL DIMENSIONS ARE IN INCHES (MILLIMETERS)

features

- 0.020" dia. light pipe aperture
- TO-72 package
- analog output

description

The CLI710 consists of an 880nm AlGaAs IRED and a phototransistor mounted on a custom TO-72 header. The IRED emits a broad radiation pattern through the formed clear epoxy lens. Radiation reflected from the target is received by a 0.020" diameter fiber optic light pipe attached to the active area of the phototransistor. For assistance or other configurations, call Clairex.

absolute maximum ratings (T_A = 25°C unless otherwise stated)

storage temperature	-40°C to +125°C
operating temperature	-40°C to +100°C
lead soldering temperature ⁽¹⁾	260°C

IRED

continuous forward DC current ⁽²⁾	35mA
reverse DC voltage	5V
continuous power dissipation ⁽³⁾	100mW

PHOTOTRANSISTOR

collector-emitter voltage	30V
emitter-collector voltage	5V
continuous power dissipation ⁽⁴⁾	100mW

note:

1. 0.06" (1.5mm) from the header for 5 seconds maximum
2. Derate linearly 0.37mA/°C from 25°C free air temperature to T_A = +100°C.
3. Derate linearly 1.07mW/°C from 25°C free air temperature to T_A = +100°C.
4. Derate linearly 1.07mW/°C from 25°C free air temperature to T_A = +100°C.

electrical characteristics (T _A = 25°C and V _{CC} = 5.0V unless otherwise noted)						
symbol	parameter	min	typ	max	units	test conditions
Input IRED						
V _F	Forward voltage	-	1.50	1.65	V	I _F = 20mA
I _R	Reverse current	-	-	10	μA	V _R = 5V
Output Phototransistor						
V _{(BR)CEO}	Collector-emitter breakdown voltage	30	-	-	V	I _C = 1mA, I _F = 0, E _e = 0
V _{(BR)ECO}	Emitter-collector breakdown voltage	5.0	-	-	V	I _E = 100μA, I _F = 0, E _e = 0
I _D	Dark current	-	-	20	nA	V _{CE} = 10V, I _F = 0, E _e = 0
Coupled						
I _L	Light current ⁽⁴⁾	150	250	-	μA	V _{CE} = 5V, I _F = 20mA, d = 0.030"
I _{CX (ratio)}	Crosstalk ratio ⁽⁵⁾	3	10	-		V _{CE} = 5V, I _F = 20mA

- notes: 4. Measured using a Kodak 90% diffuse reflectance neutral white test card.
5. No reflective surface. I_{CX(ratio)} = I_{L(μA)}/I_{CX(μA)}.